



THE UNIVERSITY OF TOKYO

# Simulation Study on SiW ECAL optimization

**Guard ring / PCB thickness  
Dead pixel**

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# + Outline

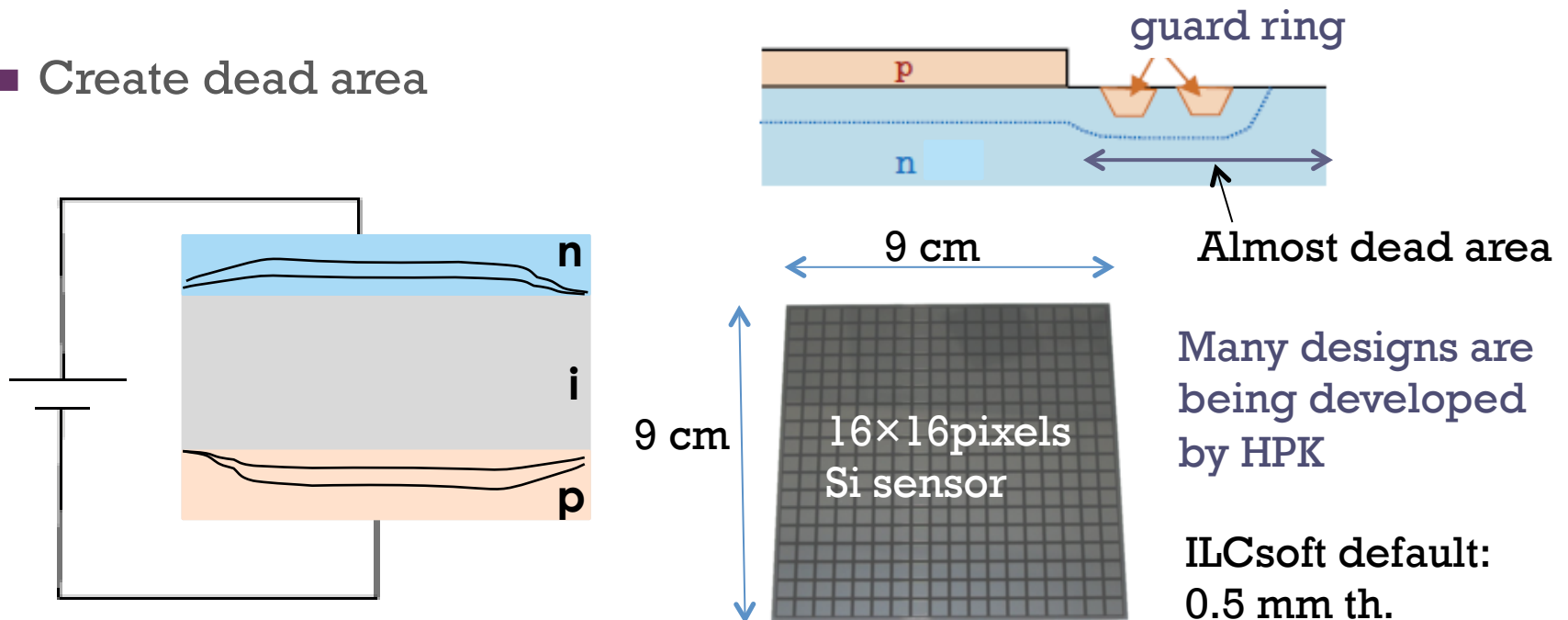
- Structural optimization of SiW ECAL
  - Width of guard ring of the sensor
  - PCB thickness
  - Effect of dead channels
- Simulation with ILD detector Model (DBD version)

# + Guard ring width problem

By C. Kozakai

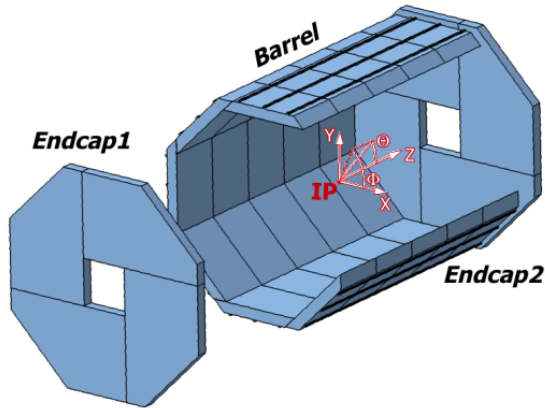
P-doped band embedded around the edge of Si pad

- **Prevent surface leakage current.**  
( $\Rightarrow$  less dark noise, fine dynamic range)
- Improve distortion of depletion layer
- Create dead area

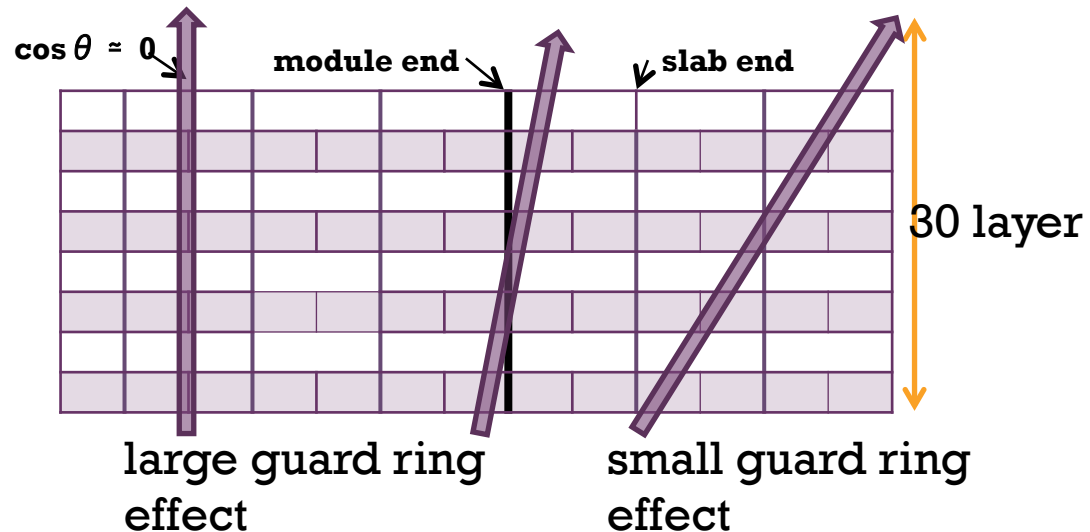
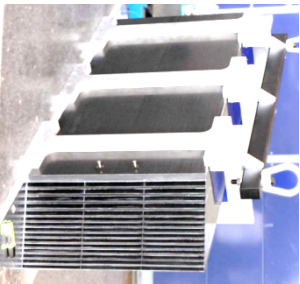
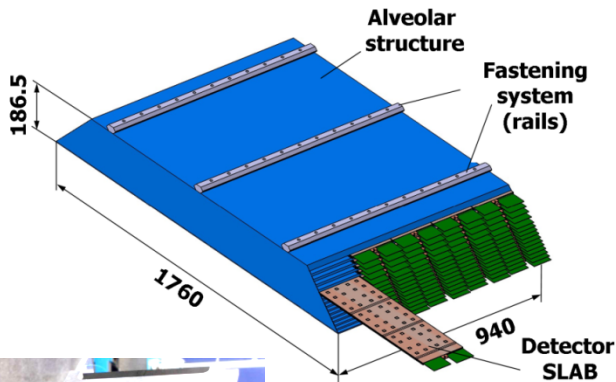




# Expected effect by guard rings

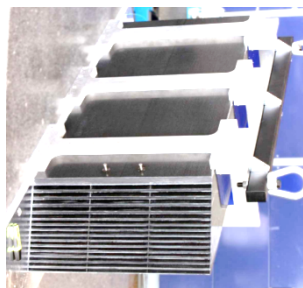
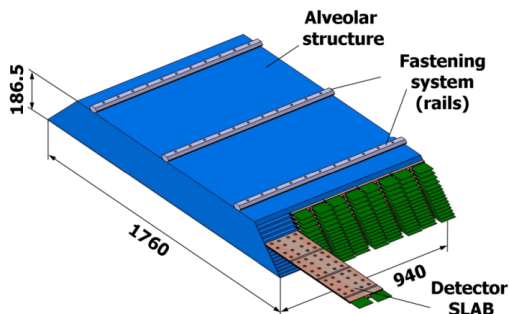
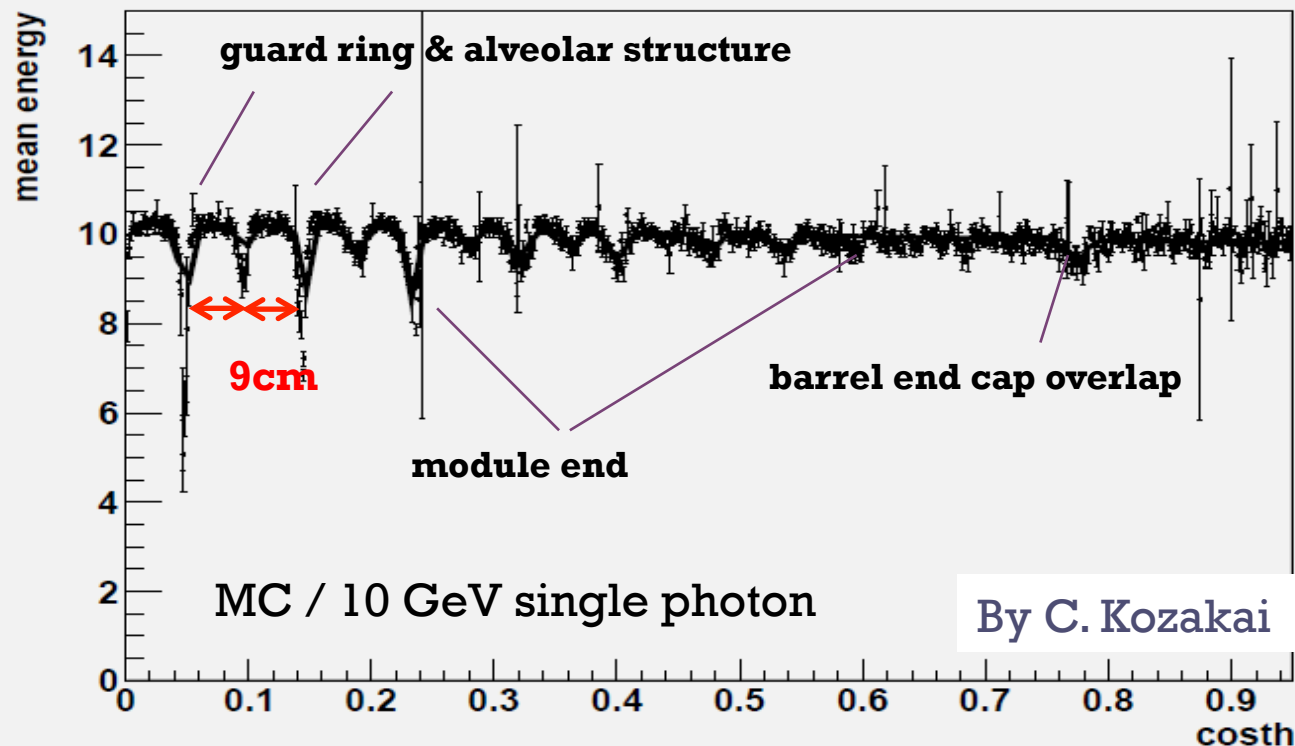


- No stagger
- Perpendicular direction ( $\cos \theta = 0$ ) has most serious effect
- Forward events will be (more or less) uniformly affected



# + Expected effect by guard rings

Mean energy with MC 10GeV single photon @ 2mm GR th.

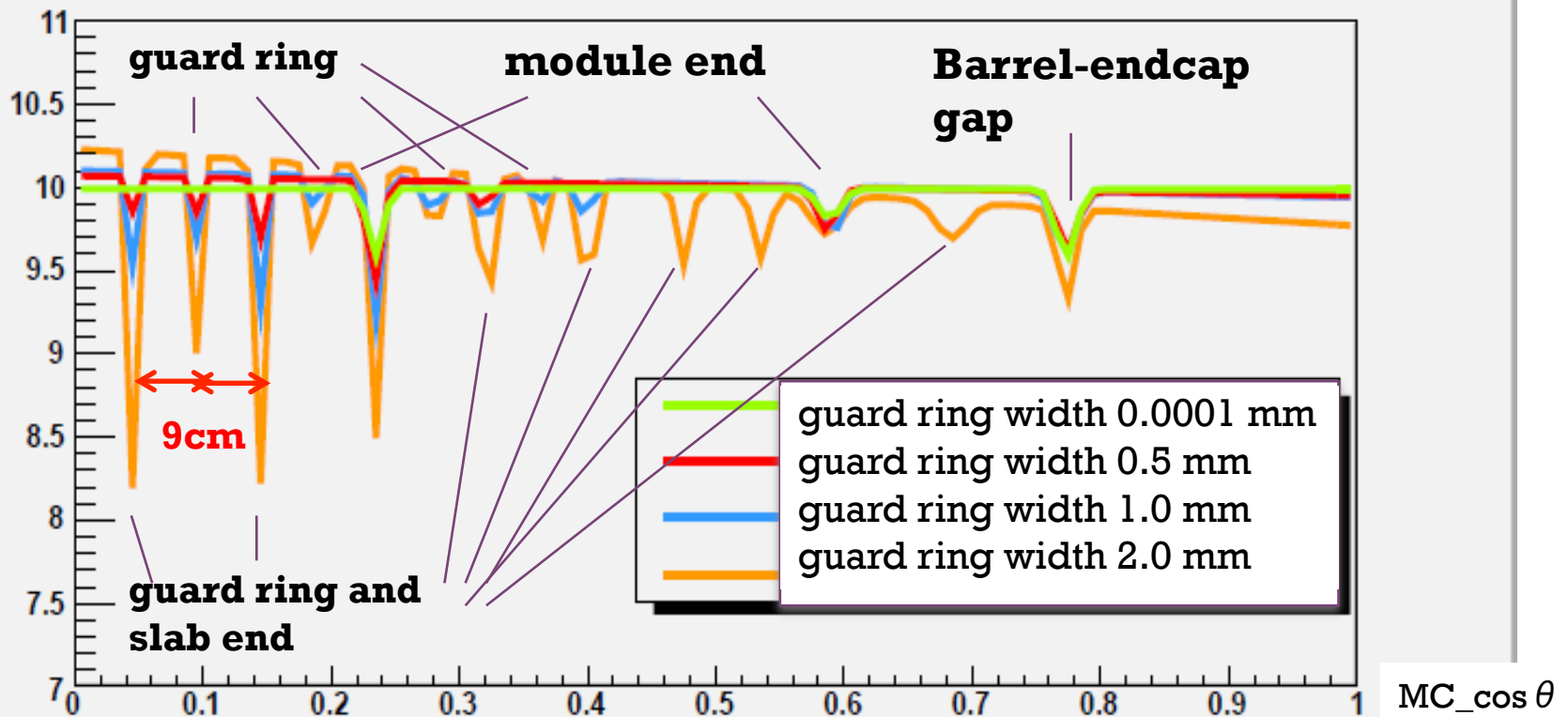


- Gaps due to module ends / supporting structure give the same effect

# + Expected effect by guard rings

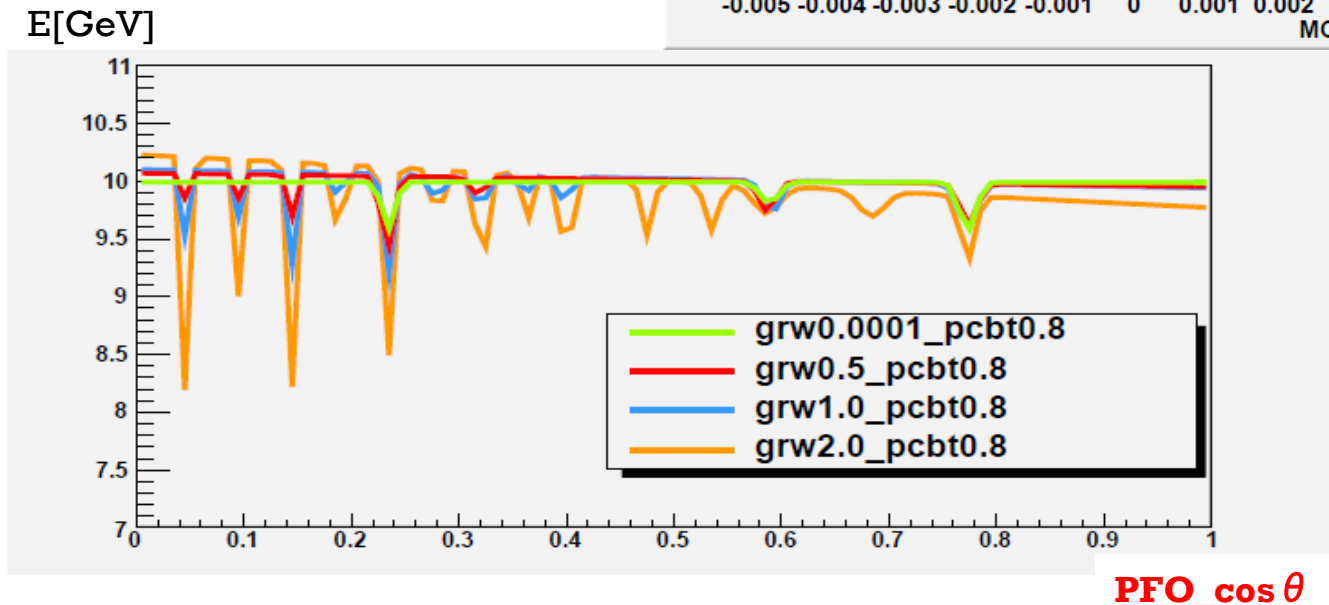
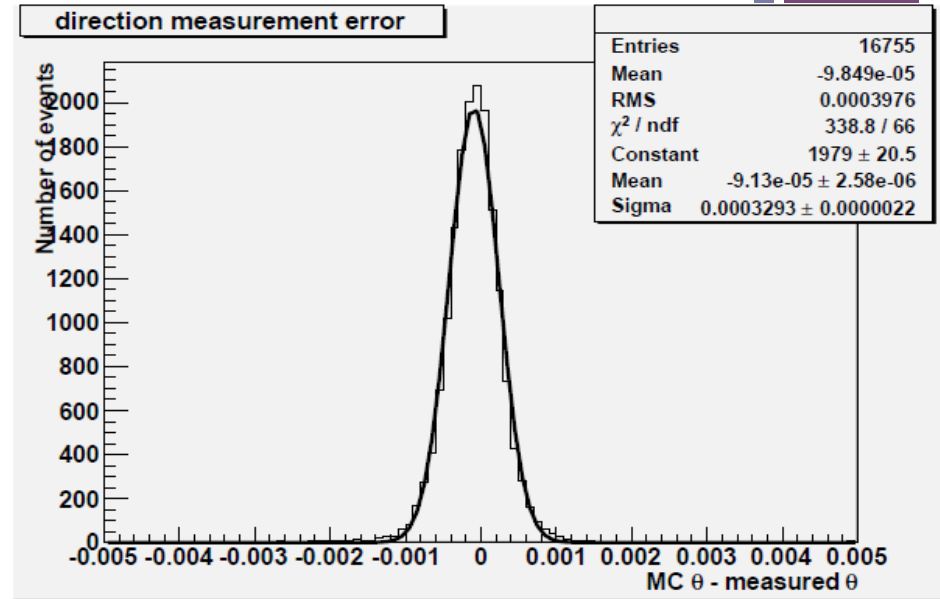
- Energy drop  $\sim 10\%$  @ 1.0mm,  $\sim 20\%$  @ 2.0mm
- Linear decrease: More Prob(encounter gaps) in forward evt

E[GeV]



# + Angular correction

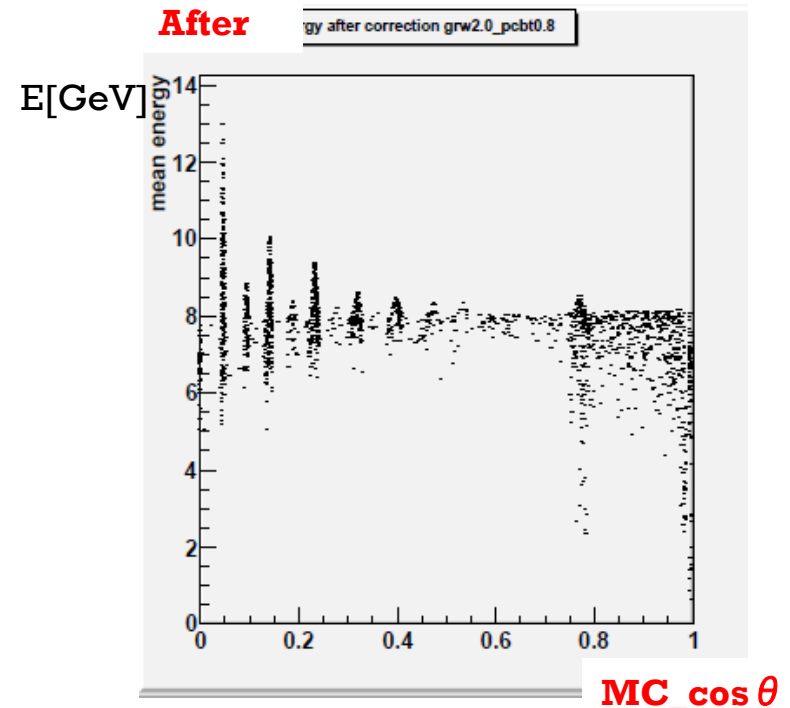
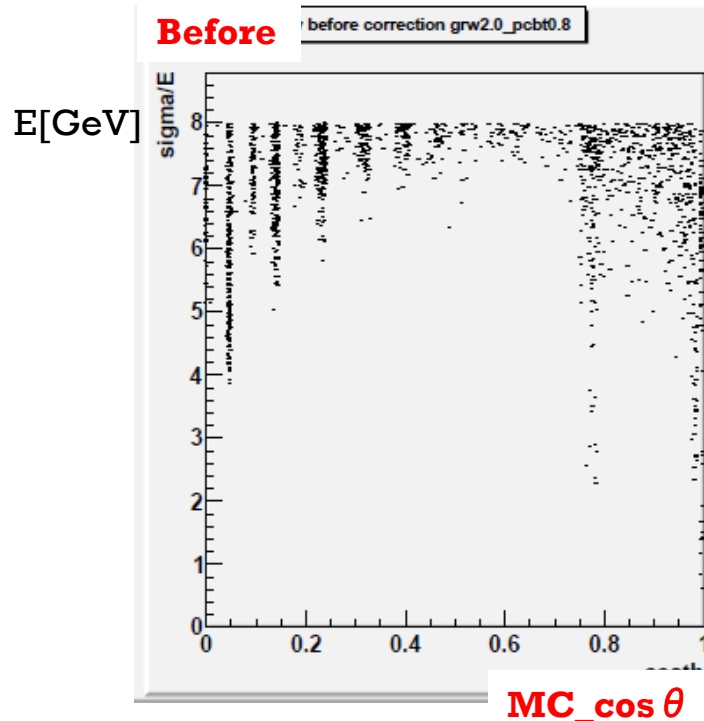
- Particle orientation is reconstructed by Pandora
- Precision of  $\theta_{\text{pfo}} \sim 3.3 \times 10^{-4}$  rad, sufficient to use for angular correction  $\theta$ .
- Fit by Linear + Gaussians



# + Angular correction

- Most of the gap events are improved to some extent
- Not completely due to bad precision of  $\theta$  around the gaps

E\_ECAL < 8 GeV with 10 GeV single photon @ 2mm GR th.

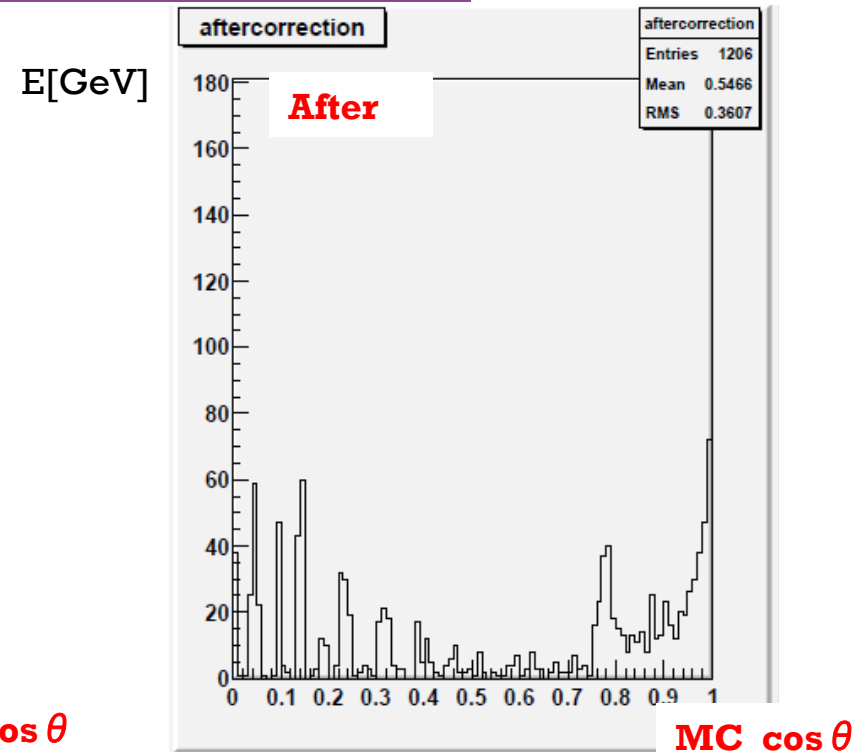
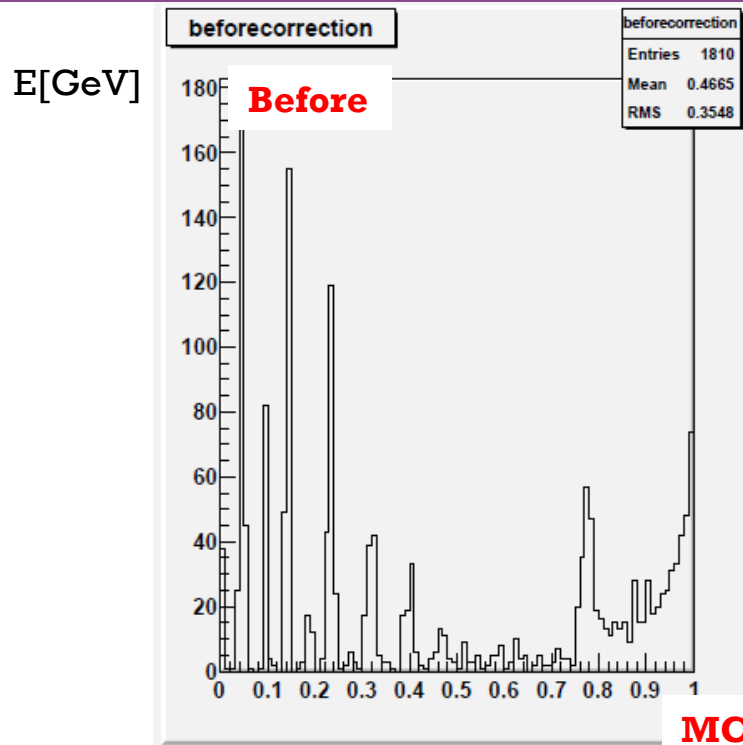




# + Angular correction

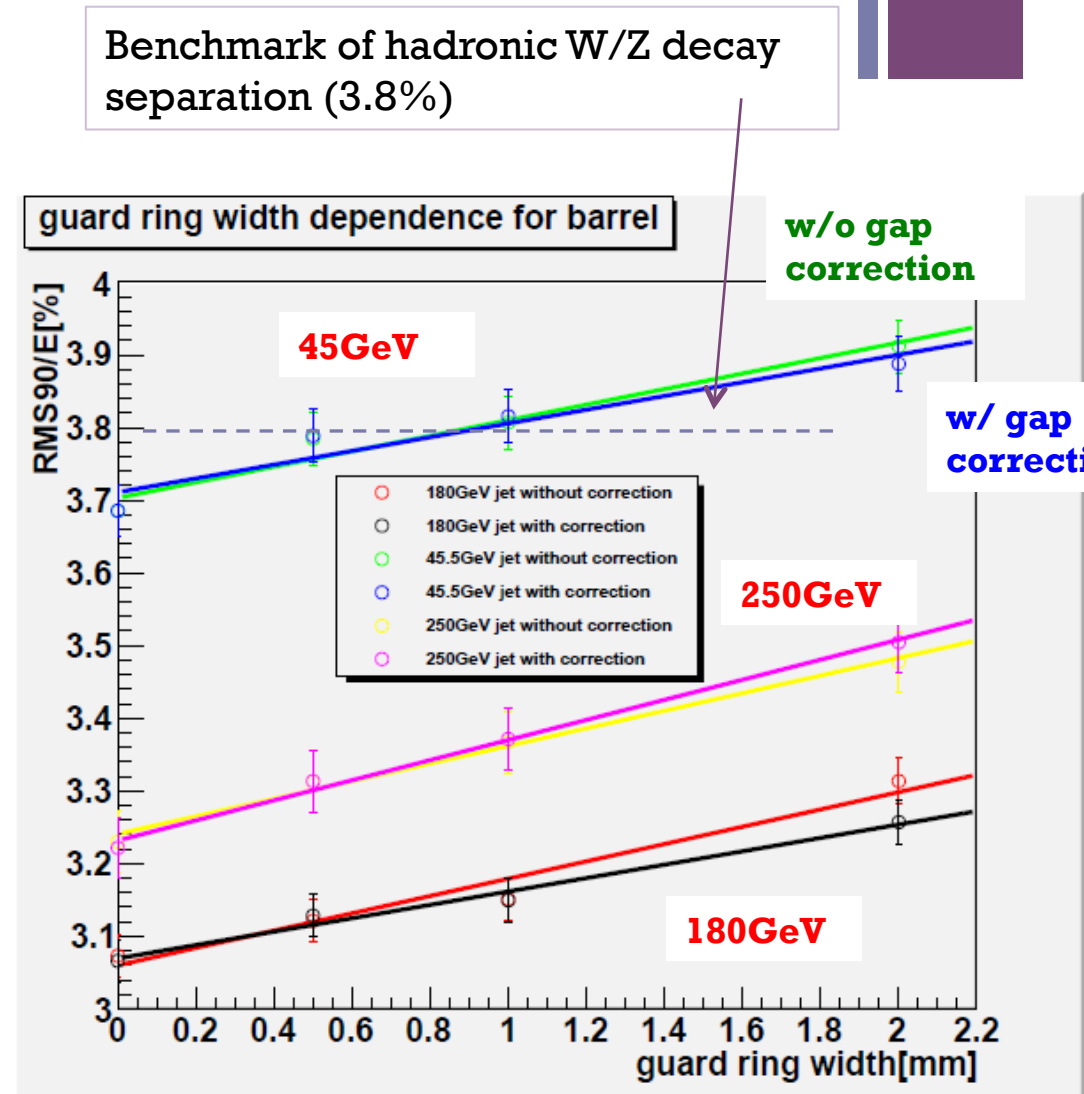
- Precision of  $\theta_{\text{pfo}} \sim 3.3 \times 10^{-4}$  rad, **sufficient to use for angular correction  $\theta$** .
- Some events are over-corrected due to bad precision of  $\theta$  around the gaps

Number of E\_ECAL < 8 GeV with 10 GeV single photon @ 2mm GR th.



# + JER VS guard ring width

- $Z \rightarrow uds$  jets
- Barrel events only  
( $\cos \theta < 0.7$ )
- JER increases as guard ring width increase.
- About  $\sim 6\%$  difference between 0 mm and 2 mm.
- Angular correction also helps resolution



# + PCB Thickness

By C. Kozakai

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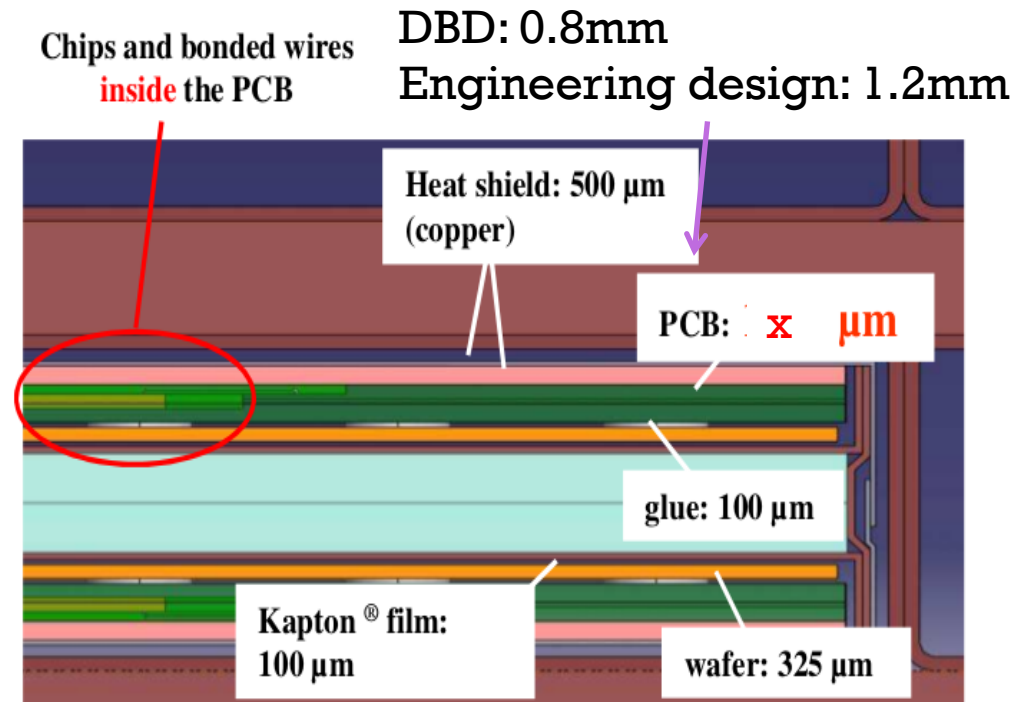
■ **Thick PCB will increase lateral shower size.**

→ Heavier overlap of shower particles

→ Confusion  $\uparrow \uparrow$  JER is expected to be worse (especially in high E)

However, there is still much **industrial difficulty in producing thin, stable PCB.**

The effect to single particle should not very much



# +JER dependence on PCB thickness

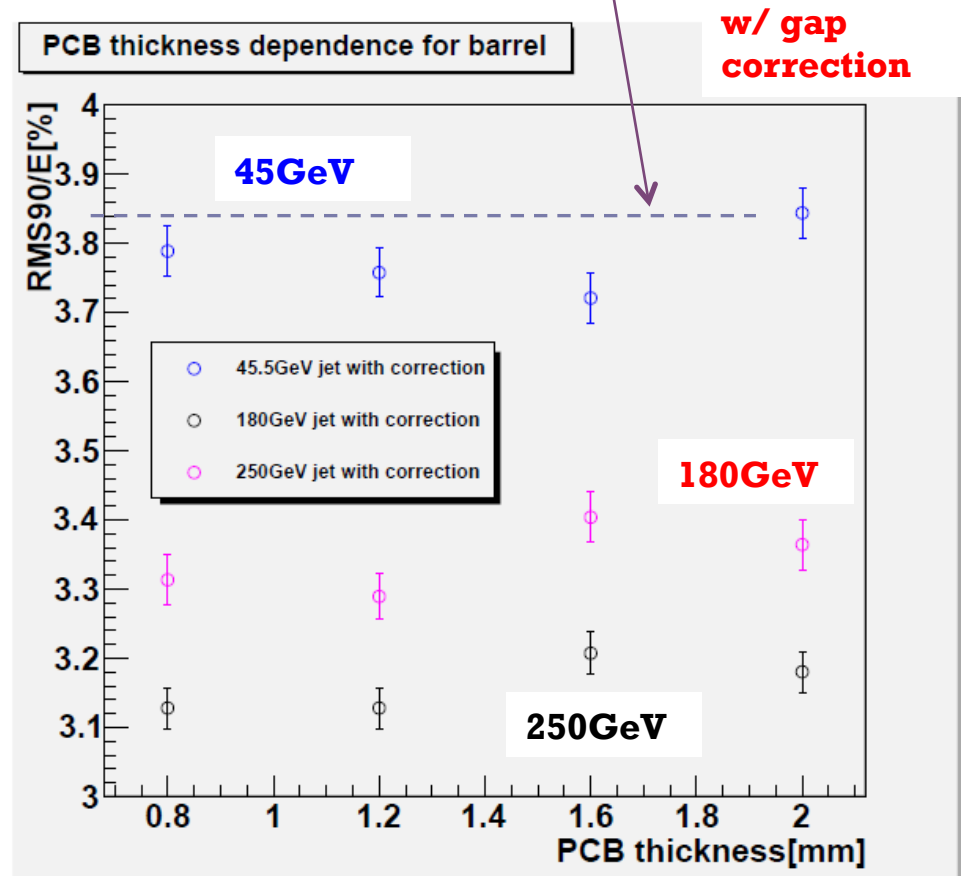
- **No significant dependence** is seen.

(Note)

We kept the size of the other modules in this study.

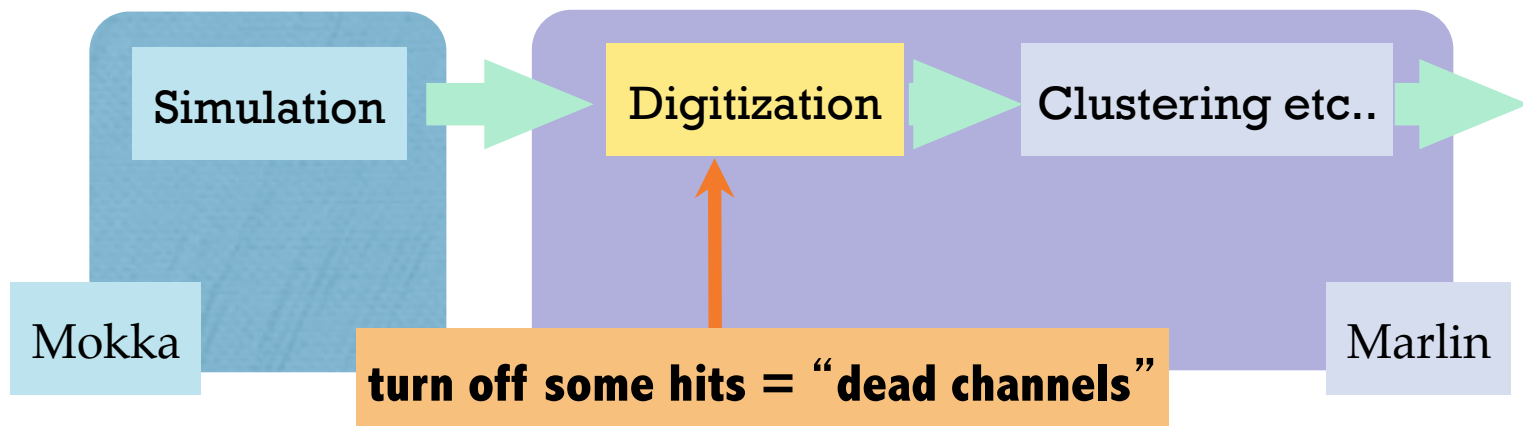
→ Whole detector size is bigger than default

Benchmark for separation of W/Z hadronic decay (3.8%)



# Dead channels effect

- If a few % dead cell is OK, we can increase yield for Si sensor and reduce cost.
- Some of the readout chip may be broken down during construction or experiment.
- Switch hits randomly in digitization :

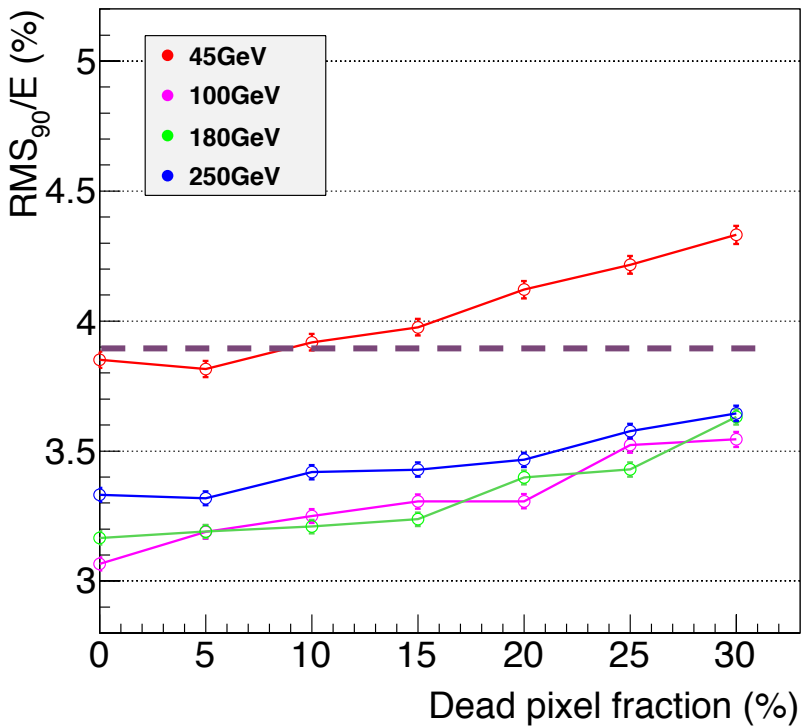


Assume dead channel distributes uniformly in the detector

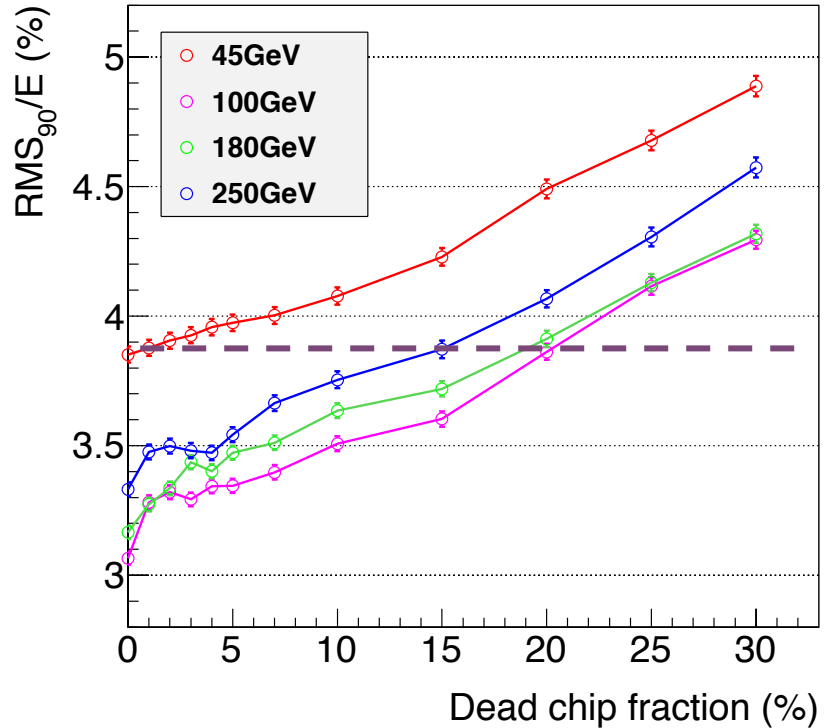


# JER vs dead pixels / chips fraction

**Dead pixels**



**Dead chips**



- Small effect with under 10 % of dead pixels, 5% of dead chips
  - ECAL resolution does go bad but not sensitive to JER
  - No serious breakdown. PFA is very robust against dead channels



# Summary

- The effect of guard ring, PCB thickness and dead pixel(chip) was studied.
- Guard ring makes JER worse ( $\sim 6\%$  @2mm)
- With different PCB thickness, no significant JER change was seen.
- 10 % of dead pixels / 5% of dead chips have very little effect on JER.
- PFA works very robustly

# + Back up



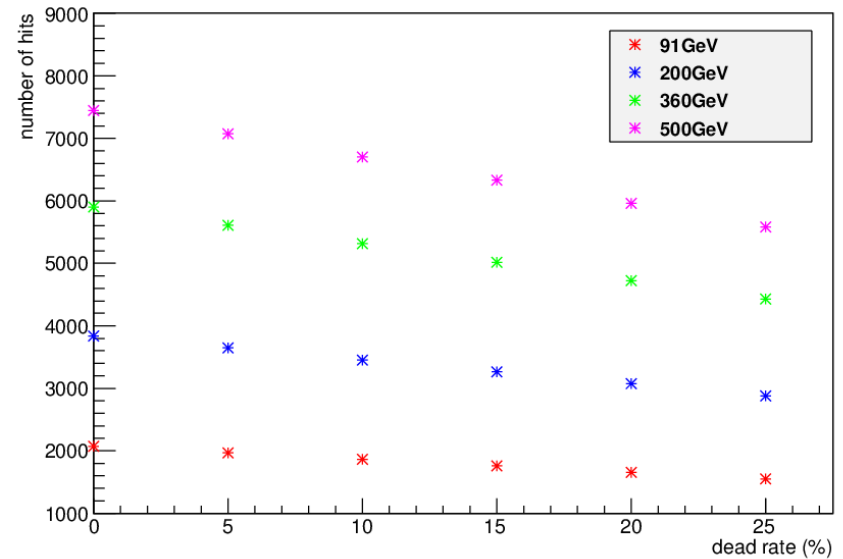


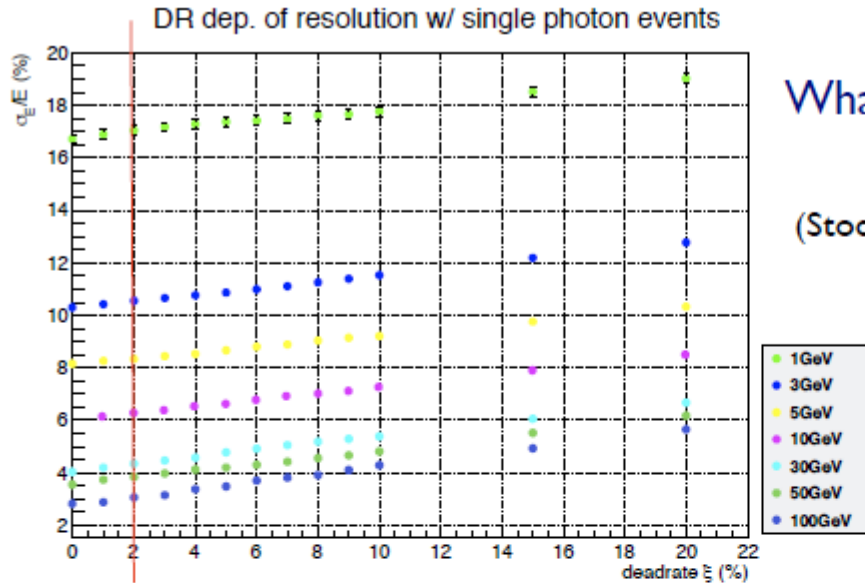
# Dead pixel rate – Number of ECAL hit

- ECAL hits decreases with dead pixel rate

# of  
ECAL hits

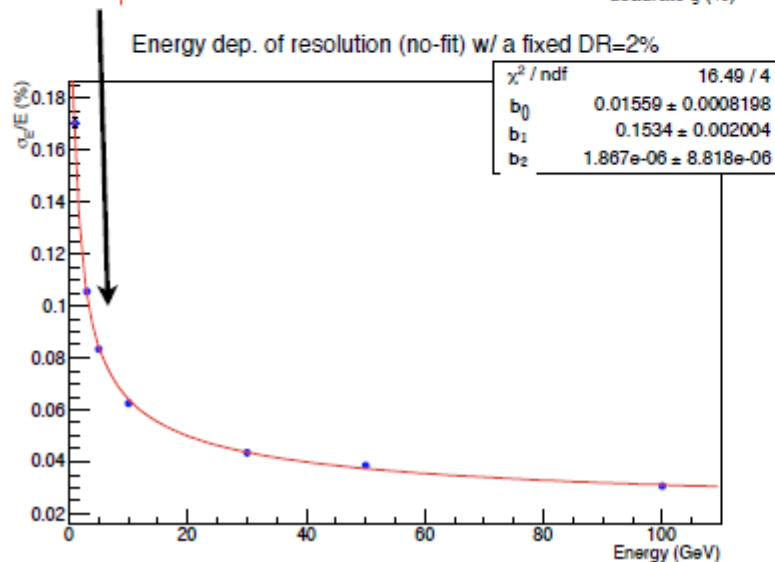
Dead rate dep. on number of hits in a jet





What component of  
energy resolution grows?  
(Stochastic term, constant term, linear term etc.)

Slice & fit with each dead rate ( $\xi$ )



Fitting function:

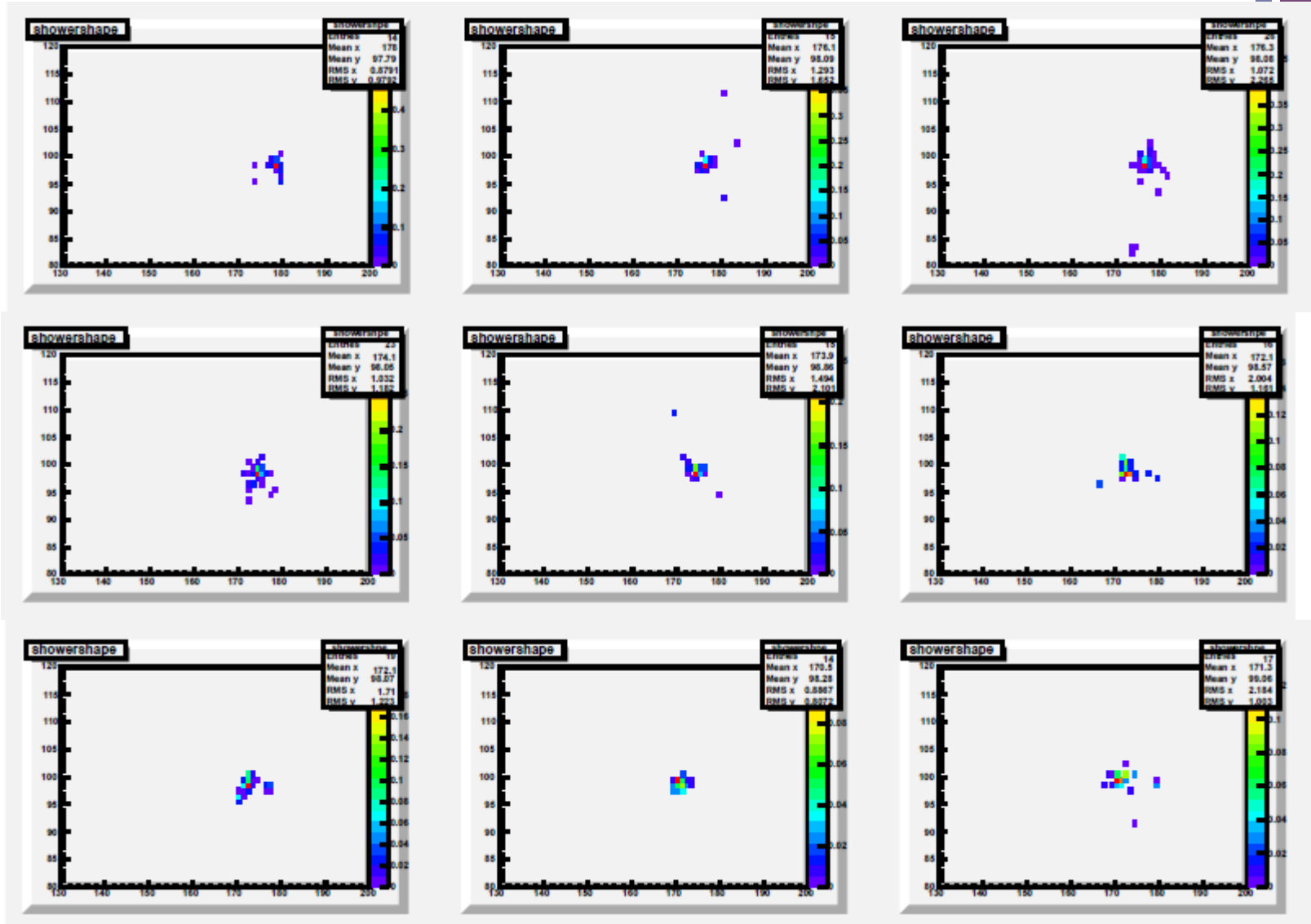
Stochastic term

Const. term

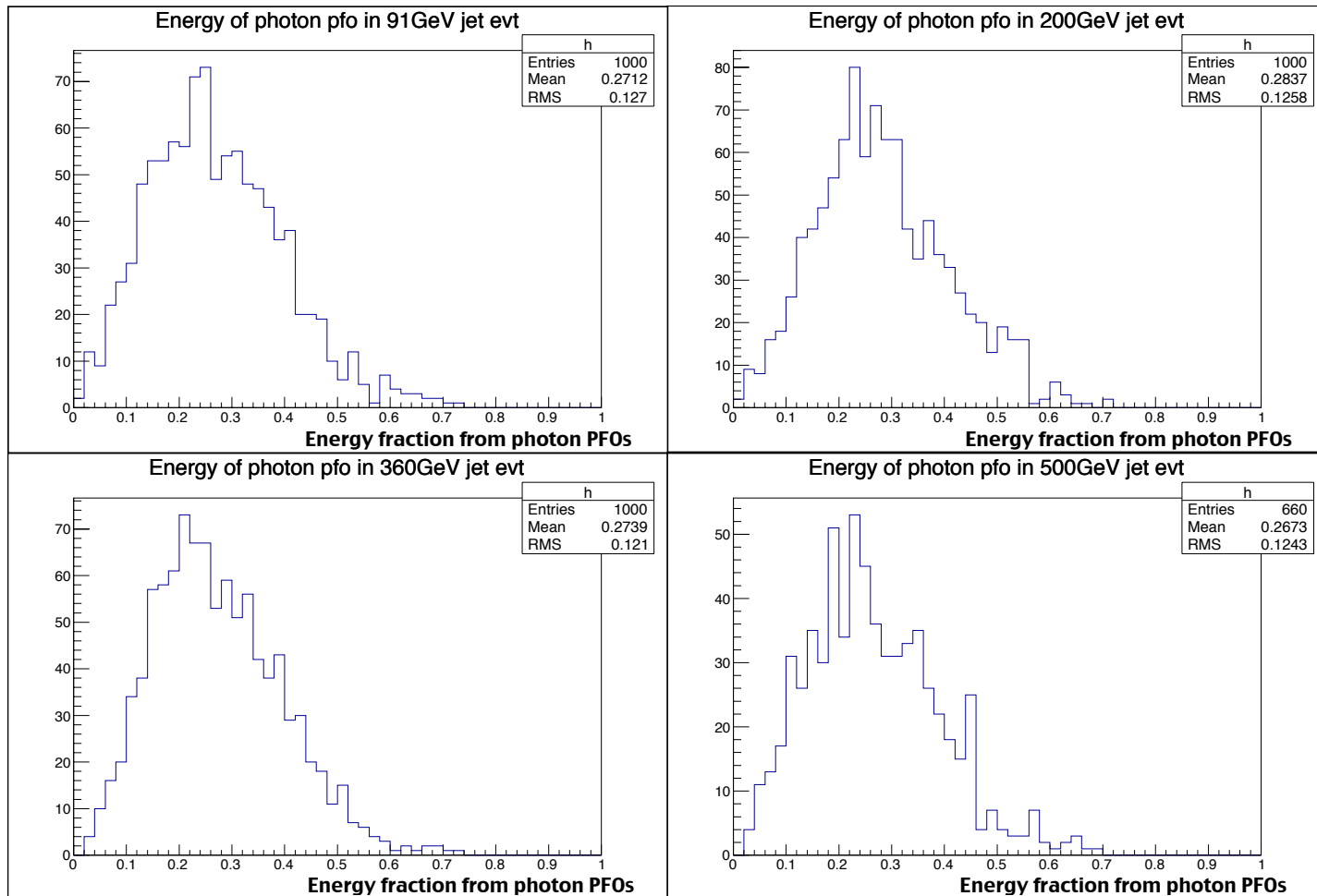
(~0)

$$\frac{\sigma E}{E} = b_0(\xi) \oplus \frac{b_1(\xi)}{\sqrt{E}} \oplus \frac{b_2(\xi)}{E}$$

# + Photon shower shape in ECAL

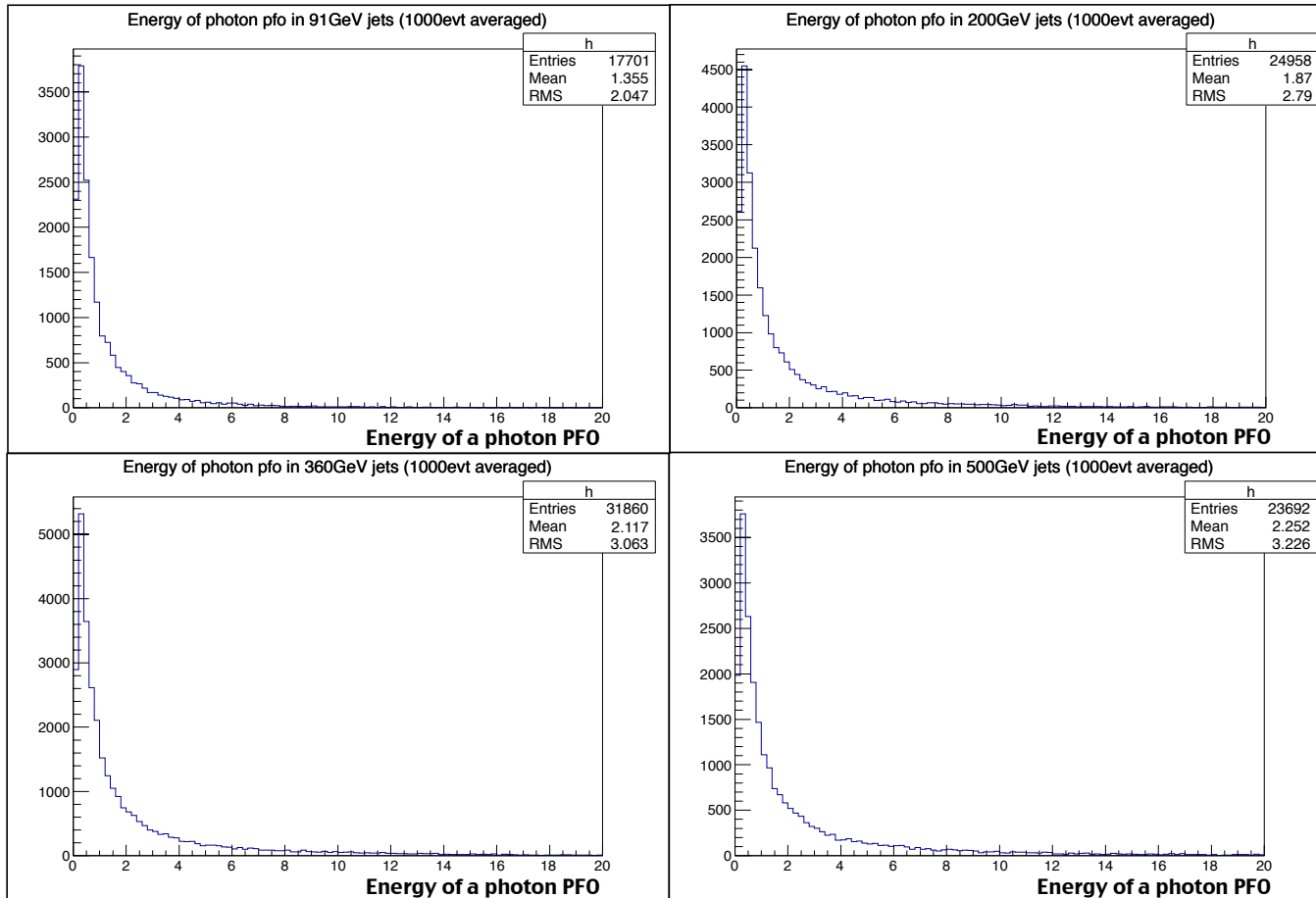


# + Photon Energy fraction in a jet



■ 20%~30% on average (large fluctuation by events)

# + Energy of a photon pfo in a jet



■ Mostly under 2~3GeV

Soft photon PFOs give the dominant contribution to neutral energy in a jet

The energy resolution is determined mainly by stochastic term

## Simple estimation of JER

$$\sigma_j \sim \sqrt{N_c \sigma_c^2 + N_\gamma \sigma_\gamma^2 + N_h \sigma_h^2}$$

$$\sim \sqrt{N_\gamma \sigma_\gamma^2 + N_h \sigma_h^2}$$

$$\sigma_h \sim 0.55 \sqrt{E_h (\text{GeV})}$$

Assume a typical **45 GeV** jet

$$N_\gamma = 9, N_h = 2,$$

$$E_\gamma = 1.4 \text{ GeV}, E_h = 3.0 \text{ GeV}$$

(See later slides)

$$\sigma_\gamma = E_\gamma \sqrt{b_0^2(\xi) + \left(\frac{b_1(\xi)}{\sqrt{E_\gamma}}\right)^2}$$

( $\xi$ : dead rate)

(pixel) (←fit with plots in page7→) (chip)

$$b_0(\xi) = 1.6 (1 + 12\xi) (\%) \quad b_0(\xi) = 1.6 (1 + 28\xi) (\%)$$

$$b_1(\xi) = \frac{17.4}{\sqrt{1 - \xi}} (\%) \quad b_1(\xi) = \frac{17.4}{\sqrt{1 - 1.5\xi}} (\%)$$

5% dead	$\sigma_\gamma/E$ (%)	$\sigma_j/E_j$ (%)
pix	15.6	3.50
chip	16.5	3.55

10% dead	$\sigma_\gamma/E$ (%)	$\sigma_j/E_j$ (%)
pix	16.5	3.55
chip	18.7	3.70

20% dead	$\sigma_\gamma/E$ (%)	$\sigma_j/E_j$ (%)
pix	18.6	3.70
chip	24.3	4.13

30% dead	$\sigma_\gamma/E$ (%)	$\sigma_j/E_j$ (%)
pix	21.2	3.89
chip	31.1	4.73

Error bar of JER in simulation (1000 events)  $\sim 0.2\text{-}0.3\%$  for each point